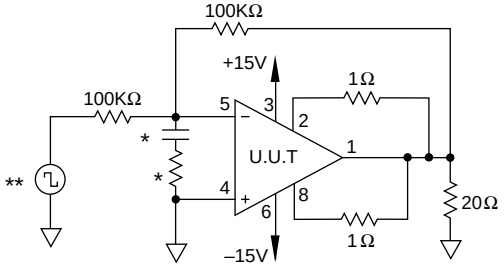
SG	PARAMETER	SYMBOL	TEMP.	POWER	TEST CONDITIONS	MIN	MAX	UNITS
1	Quiescent Current	I_Q	25°C	±28V	V_{IN} = 0, A_V = 100		5	mA
1	Input Offset Voltage	V_{OS}	25°C	±28V	V_{IN} = 0, A_V = 100		±10	mV
1	Input Offset Voltage	V_{OS}	25°C	±10V	V_{IN} = 0, A_V = 100		±17.2	mV
1	Input Offset Voltage	V_{OS}	25°C	±30V	V_{IN} = 0, A_V = 100		±10.8	mV
1	Input Bias Current, +IN	$+I_B$	25°C	±28V	V_{IN} = 0		±40	nA
1	Input Bias Current, –IN	$–I_B$	25°C	±28V	V_{IN} = 0		±40	nA
1	Input Offset Current	I_{OS}	25°C	±28V	V_{IN} = 0		±10	nA
3	Quiescent Current	I_Q	–55°C	±28V	V_{IN} = 0, A_V = 100		5	mA
3	Input Offset Voltage	V_{OS}	–55°C	±28V	V_{IN} = 0, A_V = 100		±15.2	mV
3	Input Offset Voltage	V_{OS}	–55°C	±10V	V_{IN} = 0, A_V = 100		±22.4	mV
3	Input Offset Voltage	V_{OS}	–55°C	±30V	V_{IN} = 0, A_V = 100		±16	mV
3	Input Bias Current, +IN	$+I_B$	–55°C	±28V	V_{IN} = 0		±72	nA
3	Input BiasCurrent, –IN	$–I_B$	–55°C	±28V	V_{IN} = 0		±72	nA
3	Input Offset Current	I_{OS}	–55°C	±28V	V_{IN} = 0		±26	nA
2	Quiescent Current	I_Q	125°C	±28V	V_{IN} = 0, A_V = 100		7	mA
2	Input Offset Voltage	V_{OS}	125°C	±28V	V_{IN} = 0, A_V = 100		±16.5	mV
2	Input Offset Voltage	V_{OS}	125°C	±10V	V_{IN} = 0, A_V = 100		±23.7	mV
2	Input Offset Voltage	V_{OS}	125°C	±30V	V_{IN} = 0, A_V = 100		±17.3	mV
2	Input Bias Current, +IN	$+I_B$	125°C	±28V	V_{IN} = 0		±80	nA
2	Input Bias Current, –IN	$–I_B$	125°C	±28V	V_{IN} = 0		±80	nA
2	Input Offset Current	I_{OS}	125°C	±28V	V_{IN} = 0		±30	nA
4	Output Voltage, I_O = 5A	V_O	25°C	±18.3V	R_L = 2.07Ω	10.3		V
4	Output Voltage, I_O = 50mA	V_O	25°C	±30V	R_L = 500Ω	25		V
4	Output Voltage, I_O = 2A	V_O	25°C	±30V	R_L = 12Ω	24		V
4	Current Limits	I_{CL}	25°C	±18V	R_L = 12Ω, R_{CL} = 1Ω	.54	.86	A
4	Stability/Noise	E_N	25°C	±28V	R_L = 500Ω, A_V = 1, C_L = 10nF		1	mV
4	Slew Rate	SR	25°C	±28V	R_L = 500Ω	1	10	V/µs
4	Open Loop Gain	A_{OL}	25°C	±28V	R_L = 500Ω, F = 10Hz	91		dB
4	Common Mode Rejection	CMR	25°C	±15V	R_L = 500Ω, F = DC, V_{CM} = ±9V	70		dB
6	Output Voltage, I_O = 5A	V_O	–55°C	±18.3V	R_L = 2.07Ω	10.3		V
6	Output Voltage, I_O = 50mA	V_O	–55°C	±30V	R_L = 500Ω	25		V
6	Output Voltage, I_O = 2A	V_O	–55°C	±30V	R_L = 12Ω	24		V
6	Stability/Noise	E_N	–55°C	±30V	R_L = 500Ω, A_V = 1, C_L = 10nF		1	mV
6	Slew Rate	SR	–55°C	±28V	R_L = 500Ω	1	10	V/µs
6	Open Loop Gain	A_{OL}	–55°C	±28V	R_L = 500Ω, F = 10Hz	91		dB
6	Common Mode Rejection	CMR	–55°C	±15V	R_L = 500Ω, F = DC, V_{CM} = ±9V	70		dB
5	Output Voltage, I_O = 3A	V_O	125°C	±11.3V	R_L = 2.07Ω	6.3		V
5	Output Voltage, I_O = 50mA	V_O	125°C	±30V	R_L = 500Ω	25		V
5	Output Voltage, I_O = 2A	V_O	125°C	±30V	R_L = 12Ω	24		V
5	Stability/Noise	E_N	125°C	±28V	R_L = 500Ω, A_V= 1, C_L = 10nF		1	mV
5	Slew Rate	SR	125°C	±28V	R_L = 500Ω	1	10	V/µs
5	Open Loop Gain	A_{OL}	125°C	±28V	R_L = 500Ω, F = 10Hz	91		dB
5	Common Mode Rejection	CMR	125°C	±15V	R_L = 500Ω, F = DC, V_{CM} = ±9V	70		dB

BURN IN CIRCUIT



* These components are used to stabilize device due to poor high frequency characteristics of burn in board.

** Input signals are calculated to result in internal power dissipation of approximately 2.1W at case temperature = 125°C.

